

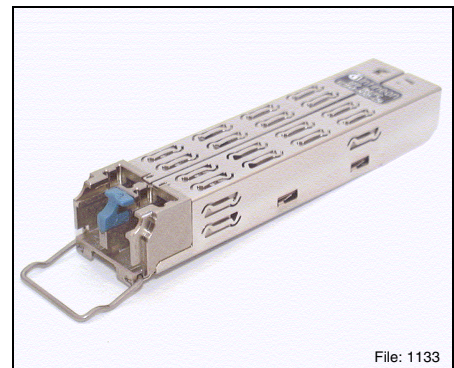
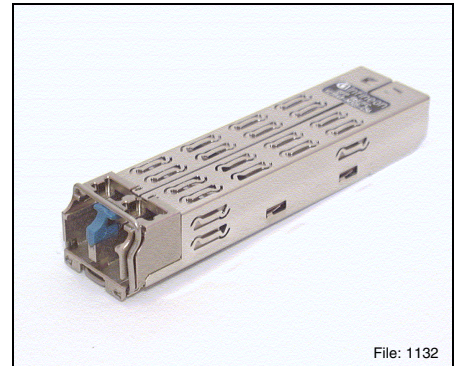
**iSFP - Intelligent Small Form-factor Pluggable  
Single Mode 1300 nm 20 km  
2.125/1.0625 Gbit/s Fibre Channel  
1.25 Gigabit Ethernet Transceiver with LC™ Connector**

**V23848-M15-C656**

## Preliminary Data Sheet

### Features

- Small Form-factor Pluggable (SFP) MSA compliant transceiver<sup>1)</sup>
- Fully SFF-8472 MSA compliant<sup>1)</sup>
- Incorporating Intelligent – Digital Diagnostic Monitoring Interface
  - Internal calibration implementation
- Advanced release mechanisms
  - Easy access, even in belly to belly applications
  - Wire handle release for simplicity
- Color coded blue tab (single mode)
- PCI height compliant
- Excellent EMI performance
  - Common ground concept
- RJ-45 style LC™ connector system
- Single power supply (3.3 V)
- Low power consumption
- Small size for high channel density
- UL-94 V-0 certified
- ESD Class 1C per JESD22-A114-B (MIL-STD 883D Method 3015.7)
- Compliant with FCC (Class B) and EN 55022
- For distances of up to 20 km
- DFB laser, PIN photo diode
- Class 1 FDA and IEC laser safety compliant
- AC/AC Coupling according to MSA
- Extended operating temperature range of –20°C to 80°C
- SFP evaluation kit V23848-S5-V4 available upon request
- Recommendation: Infineon Cage one-piece design V23838-S5-N1 for press fit and/or solderable or V23838-S5-N1-BB for belly to belly applications



<sup>1)</sup> MSA documentation can be found at [www.infineon.com/fiberoptics](http://www.infineon.com/fiberoptics) under Transceivers, SFP Transceivers.

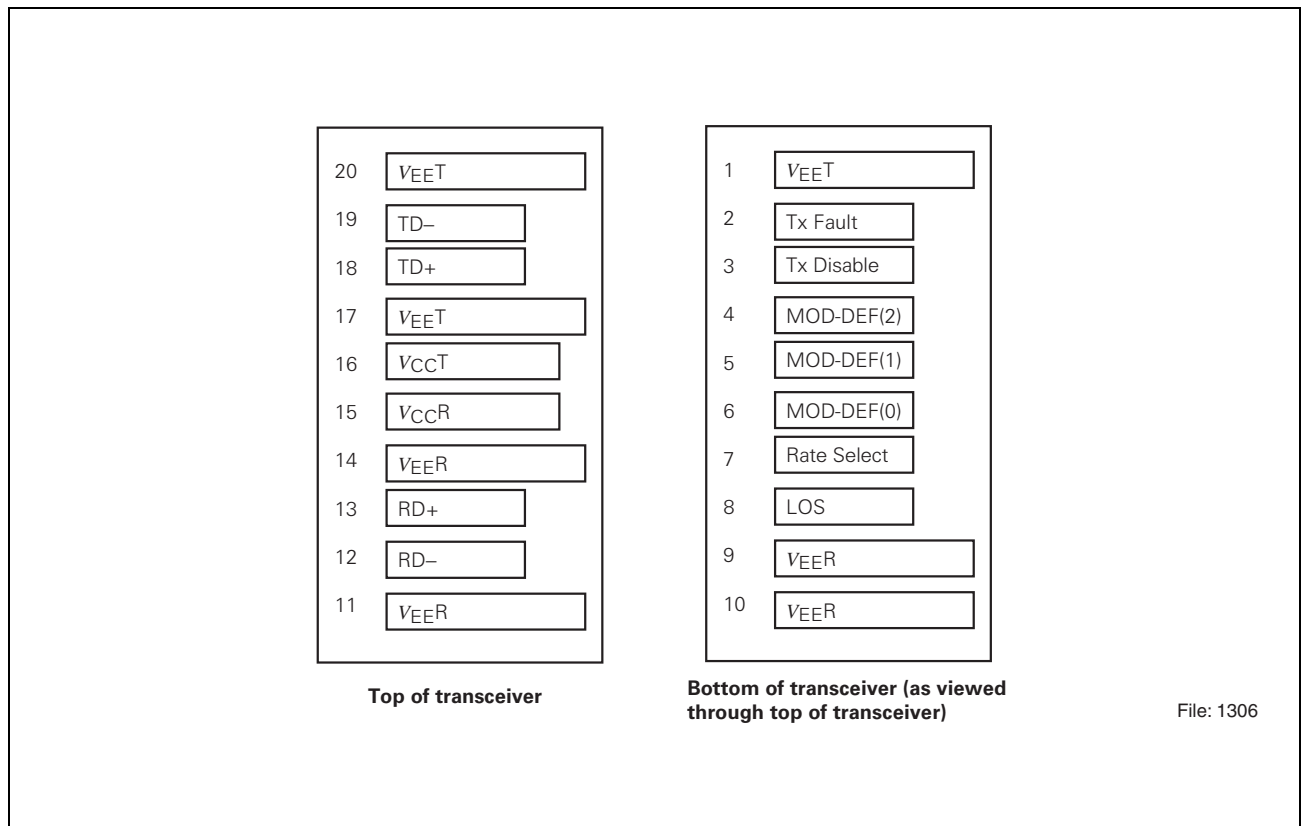
For ordering information see next page.

LC™ is a trademark of Lucent.

**Ordering Information**

Part Number	Extraction Method
V23848-M15-C656	Wire handle

**Pin Configuration**



**Figure 1 iSFP Transceiver Electrical Pad Layout**

**Pin Configuration**
**Pin Description**

Pin No.	Name	Logic Level	Function
1	$V_{EE}T$	N/A	Transmitter Ground <sup>1)</sup>
2	Tx Fault	LVTTTL	Transmitter Fault Indication <sup>2) 8)</sup>
3	Tx Disable	LVTTTL	Transmitter Disable <sup>3)</sup>
4	MOD-DEF(2)	LVTTTL	Module Definition 2 <sup>4) 8)</sup>
5	MOD-DEF(1)	LVTTTL	Module Definition 1 <sup>5) 8)</sup>
6	MOD-DEF(0)	N/A	Module Definition 0 <sup>6) 8)</sup>
7	Rate Select	N/A	Not connected
8	LOS	LVTTTL	Loss Of Signal <sup>7) 8)</sup>
9	$V_{EE}R$	N/A	Receiver Ground <sup>1)</sup>
10	$V_{EE}R$	N/A	Receiver Ground <sup>1)</sup>
11	$V_{EE}R$	N/A	Receiver Ground <sup>1)</sup>
12	RD-	LVPECL	Inv. Received Data Out <sup>9)</sup>
13	RD+	LVPECL	Received Data Out <sup>9)</sup>
14	$V_{EE}R$	N/A	Receiver Ground <sup>1)</sup>
15	$V_{CC}R$	N/A	Receiver Power
16	$V_{CC}T$	N/A	Transmitter Power
17	$V_{EE}T$	N/A	Transmitter Ground <sup>1)</sup>
18	TD+	LVPECL	Transmit Data In <sup>10)</sup>
19	TD-	LVPECL	Inv. Transmit Data In <sup>10)</sup>
20	$V_{EE}T$	N/A	Transmitter Ground <sup>1)</sup>

<sup>1)</sup> Common transmitter and receiver ground within the module.

<sup>2)</sup> A high signal indicates a laser fault of some kind and that laser is switched off.

<sup>3)</sup> A low signal switches the transmitter on. A high signal or when not connected switches the transmitter off.

<sup>4)</sup> MOD-DEF(2) is the data line of two wire serial interface for serial ID.

<sup>5)</sup> MOD-DEF(1) is the clock line of two wire serial interface for serial ID.

<sup>6)</sup> MOD-DEF(0) is grounded by the module to indicate that the module is present.

<sup>7)</sup> A low signal indicates normal operation, light is present at receiver input. A high signal indicates the received optical power is below the worst case receiver sensitivity.

<sup>8)</sup> Should be pulled up on host board to  $V_{CC}$  by 4.7 - 10 k $\Omega$ .

<sup>9)</sup> AC coupled inside the transceiver. Must be terminated with 100  $\Omega$  differential at the user SERDES.

<sup>10)</sup> AC coupled and 100  $\Omega$  differential termination inside the transceiver.

**Description**
**Description**

The Infineon Fibre Channel / Gigabit Ethernet single mode transceiver – part of Infineon iSFP family – is based on the Physical Medium Depend (PMD) sublayer and baseband medium, type 1000 Base-LX (long wavelength) as specified in IEEE Std 802.3 and Fibre Channel FC-PI (Rev. 13) 100-SM-LC-L for 1.0625 Gbit/s, and 200-SM-LC-L for 2.125 Gbit/s.

The appropriate fiber optic cable is 9 µm single mode fiber with LC™ connector.

**Link Length as Defined by IEEE and Fibre Channel Standards**

Fiber Type	Reach			Unit
	min. <sup>1)</sup>	typ.	max. <sup>2)</sup>	
<b>at 1.0625 Gbit/s</b>				
9 µm, SMF	2		20,000	meters
50 µm, 500 MHz*km	0.5	550		
62.5 µm, 200 MHz*km	0.5	550		
<b>at 1.25 Gbit/s</b>				
9 µm, SMF	2		5,000	meters
50 µm, 400/500 MHz*km	2		550	
62.5 µm, 500 MHz*km	2		550	
<b>at 2.125 Gbit/s</b>				
9 µm, SMF	2		20,000	meters
50 µm, 500 MHz*km	0.5	300		
62.5 µm, 200 MHz*km	0.5	150		

<sup>1)</sup> Minimum reach as defined by IEEE and Fibre Channel Standards. A 0 m link length (loop-back connector) is supported.

<sup>2)</sup> Longer reach possible depending upon link implementation.

## Description

The Infineon iSFP single mode transceiver is a single unit comprised of a transmitter, a receiver, and an LC™ receptacle.

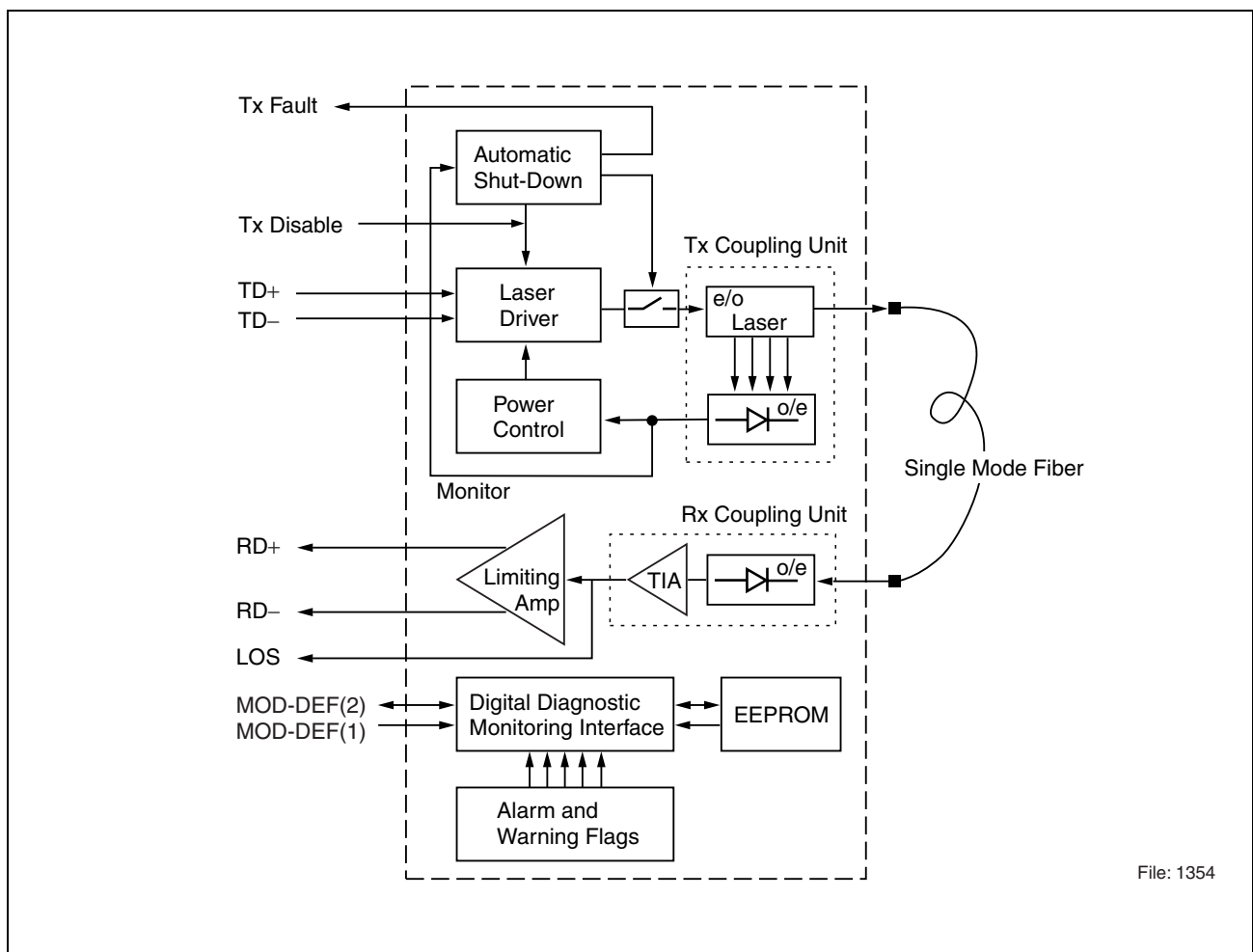
This transceiver supports the LC™ connectorization concept. It is compatible with RJ-45 style backpanels for high end datacom and telecom applications while providing the advantages of fiber optic technology.

The module is designed for low cost SAN, LAN, Fibre Channel and Gigabit Ethernet applications. It can be used as the network end device interface in mainframes, workstations, servers, and storage devices, and in a broad range of network devices such as bridges, routers, hubs, and local and wide area switches.

This transceiver operates at 2.125, 1.0625 and 1.25 Gbit/s from a single power supply (+3.3 V). The 100 Ω differential data inputs and outputs are LVPECL and CML compatible.

### Functional Description of iSFP Transceiver

This transceiver is designed to transmit serial data via single mode cable.



**Figure 2 Functional Diagram**

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## Description

The receiver component converts the optical serial data into LVPECL compatible electrical data (RD+ and RD-). The Loss Of Signal (LOS) shows whether an optical signal is present.

The transmitter converts LVPECL compatible electrical serial data (TD+ and TD-) into optical serial data. Data lines are differentially 100  $\Omega$  terminated.

The transmitter contains a laser driver circuit that drives the modulation and bias current of the laser diode. The currents are controlled by a power control circuit to guarantee constant output power of the laser over temperature and aging. The power control uses the output of the monitor PIN diode (mechanically built into the laser coupling unit) as a controlling signal, to prevent the laser power from exceeding the operating limits.

Single fault condition is ensured by means of an integrated automatic shutdown circuit that disables the laser when it detects laser fault to guarantee the laser Eye Safety.

The transceiver contains a supervisory circuit to control the power supply. This circuit makes an internal reset signal whenever the supply voltage drops below the reset threshold. It keeps the reset signal active for at least 140 milliseconds after the voltage has risen above the reset threshold. During this time the laser is inactive.

A low signal on TxDis enables transmitter. If TxDis is high or not connected the transmitter is disabled.

An enhanced Digital Diagnostic Monitoring Interface (Intelligent) has been incorporated into the Infineon Small Form-factor Pluggable (SFP) transceiver. This allows real time access to transceiver operating parameters, based on the SFF-8472.

This transceiver features Internal Calibration. Measurements are calibrated over operating temperature and voltage and must be interpreted as defined in SFF-8472.

The transceiver generates this diagnostic data by digitization of internal analog signals monitored by a new diagnostic Integrated Circuit (IC).

This diagnostic IC has inbuilt sensors to include alarm and warning thresholds. These threshold values are set during device manufacture and therefore allow the user to determine when a particular value is outside of its operating range.

Alarm and Warning Flags are given. Alarm Flags indicate conditions likely to be associated with an inoperational link and cause for immediate action. Warning Flags indicate conditions outside the normally guaranteed bounds but not necessarily causes of immediate link failures.

These enhanced features are in addition to the existing SFP features provided by the manufacturer i.e. serial number and other vendor specific data.

The serial ID interface defines a 256 byte memory map in EEPROM, accessible over a 2 wire, serial interface at the 8 bit address 1010000X (A0h).

The Digital Diagnostic Monitoring Interface makes use of the 8 bit address 1010001X (A2h), so the originally defined serial ID memory map remains unchanged and is therefore backward compatible.

**Description**
**Digital Diagnostic Monitoring Parameters**

<b>Parameter</b>	<b>Accuracy SFF-8472</b>	<b>Accuracy Actual</b>
Tx Optical Power	±3 dB	±1 dB
Rx Optical Power	±3 dB	±3 dB
Bias Current	±10%	±10%
Power Supply Voltage	±3%	±3%
Transceiver Temperature	±3°C	±3°C

**Regulatory Compliance**

<b>Feature</b>	<b>Standard</b>	<b>Comments</b>
ESD: Electrostatic Discharge to the Electrical Pins	EIA/JESD22-A114-B (MIL-STD 883D method 3015.7)	Class 1C
Immunity: Against Electrostatic Discharge (ESD) to the Duplex LC Receptacle	EN 61000-4-2 IEC 61000-4-2	Discharges ranging from ±2 kV to ±15 kV on the receptacle cause no damage to transceiver (under recommended conditions).
Immunity: Against Radio Frequency Electromagnetic Field	EN 61000-4-3 IEC 61000-4-3	With a field strength of 10 V/m, noise frequency ranges from 10 MHz to 2 GHz. No effect on transceiver performance between the specification limits.
Emission: Electromagnetic Interference (EMI)	FCC 47 CFR Part 15, Class B EN 55022 Class B CISPR 22	Noise frequency range: 30 MHz to 18 GHz

**Technical Data**
**Absolute Maximum Ratings**

Parameter	Symbol	Limit Values		Unit
		min.	max.	
Data Input Voltage	$V_{ID\ max}$		$V_{CC}+0.5$	V
Differential Data Input Voltage Swing	$V_{ID\ pk-pk}$		5	V
Storage Ambient Temperature	$T_S$	-40	85	°C
Operating Case Temperature <sup>1)</sup>	$T_A$	-40	85	°C
Storage Relative Humidity	$RH_s$	5	95	%
Operating Relative Humidity	$RH_o$	5	85	%
Supply Voltage	$V_{CC\ max}$		4	V
Data Output Current	$I_{data}$		50	mA
Receiver Optical Input Power	$Rx_P\ max$		3	dBm

<sup>1)</sup> Operating case temperature measured at transceiver hottest point.

Exceeding any one of these values may permanently destroy the device.



**Electrical Characteristics**

Parameter	Symbol	Limit Values			Unit
		min.	typ.	max.	
<b>Common</b>					
Supply Voltage	$V_{CC}-V_{EE}$	2.97	3.3	3.63	V
In-rush Current <sup>1)</sup>	$I_{IR\ max}$			30	mA
Power Dissipation	$P$			1	W
<b>Transmitter</b>					
Differential Data Input Voltage Swing <sup>2)</sup>	$V_{ID\ pk-pk}$	500		3200	mV
Tx Disable Voltage	$Tx_{Dis}$	2		$V_{CC}$	V
Tx Enable Voltage	$Tx_{En}$	$V_{EE}$		0.8	V
Tx Fault High Voltage	$Tx_{FH}$	2.4		$V_{CC}$	V
Tx Fault Low Voltage	$Tx_{FL}$	$V_{EE}$		0.5	V
Reset Threshold <sup>3)</sup>	$V_{TH}$	2.5	2.75	2.85	V
Reset Time Out <sup>3)</sup>	$t_{RES}$	140	240	300	ms
Supply Current <sup>4)</sup>	$I_{Tx}$		80	150	mA
<b>Receiver</b>					
Differential Data Output Voltage Swing <sup>5)</sup>	$V_{OD\ pk-pk}$	370	900	2000	mV
LOS Active	$LOS_A$	2.4		$V_{CC}$	V
LOS Normal	$LOS_N$	$V_{EE}$		0.5	V
Receiver 3 dB Cut-off Frequency <sup>6)</sup>				1.5	GHz
Receiver 10 dB Cut-off Frequency <sup>6)</sup>				3	GHz
Rise Time <sup>7)</sup>	$t_{R-Rx}$			t.b.d.	ps
Fall Time <sup>7)</sup>	$t_{F-Rx}$			t.b.d.	ps
Power Supply Noise Rejection <sup>9)</sup>	PSNR		100		mV <sub>pp</sub>
Supply Current <sup>4) 9)</sup>	$I_{Rx}$		100	130	mA

<sup>1)</sup> Measured with MSA recommended supply filter network (Figure 6). Maximum value above that of the steady state value.

<sup>2)</sup> Internally AC coupled. Typical 100 Ω differential input impedance.

<sup>3)</sup> Laser power is shut down if power supply is below  $V_{TH}$  and switched on if power supply is above  $V_{TH}$  after  $t_{RES}$ .

<sup>4)</sup> MSA defines maximum current at 300 mA.

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**Technical Data**

- 5) Internally AC coupled. Load  $50\ \Omega$  to GND or  $100\ \Omega$  differential. For dynamic measurement a tolerance of 50 mV should be added.
- 6) Fibre Channel PI Standard.
- 7) Measured values are 20% - 80%.
- 8) Measured using a 20 Hz to 1 MHz sinusoidal modulation with the MSA recommended power supply filter network (**Figure 6**) in place. A change in sensitivity of less than 1 dB can be typically expected.
- 9) Supply current excluding Rx output load.

**Optical Characteristics**

Parameter	Symbol	Limit Values			Unit
		min.	typ.	max.	
<b>Transmitter</b>					
Optical Modulation Amplitude <sup>1)</sup>	OMA	310			μW
Launched Power (Average) <sup>2)</sup>	$P_O$	-7		0	dBm
Extinction Ratio (Dynamic) <sup>3)</sup>	ER	9			dB
Center Wavelength <sup>1)</sup>	$\lambda_C$	1300		1320	nm
Spectral Width (rms) <sup>1)</sup>	$\sigma_I$			1	nm
Relative Intensity Noise	RIN			-120	dB/Hz
Tx Disable Laser Output Power	$P_{O-TxDis}$			t.b.d.	dBm
Data Deterministic Jitter	DDJ <sub>Tx</sub>			t.b.d.	ps
Total Jitter	TJ <sub>Tx</sub>			80	ps
Rise Time <sup>4)</sup>	$t_{R-Tx}$			t.b.d.	ps
Fall Time <sup>4)</sup>	$t_{F-Tx}$			t.b.d.	ps
<b>Receiver<sup>5)</sup></b>					
Min. Optical Modulation Amplitude <sup>6)</sup>	OMA			15	μW
Average Received Power	$P_R$			0	dBm
Sensitivity (Average Power) <sup>7)</sup> @ 2.125 Gbit/s @ 1.25 Gbit/s @ 1.0625 Gbit/s	$P_{IN}$			-21 -21 -21	dBm
LOS Assert Level <sup>8)</sup>	$P_{LOSA}$	-37			dBm
LOS Deassert Level <sup>9)</sup>	$P_{LOSD}$			-22	dBm
LOS Hysteresis	$P_{LOSA}$ $-P_{LOSD}$	0.5	1	6	dB
Input Center Wavelength	$\lambda_C$	1260		1580	nm
Optical Return Loss	ORL	12			dB
Data Deterministic Jitter	DDJ <sub>Rx</sub>			t.b.d.	ps
Total Jitter	TJ <sub>Rx</sub>			t.b.d.	ps

<sup>1)</sup> FC-PI Rev. 13 defines triple trade off curves.

<sup>2)</sup> Into single mode fiber, 9 μm diameter.

<sup>3)</sup> For Gigabit Ethernet only.

<sup>4)</sup> Measured at nominal data rate. These are unfiltered 20% - 80% values.

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**Technical Data**

- 5) Receiver characteristics are measured with a worst case reference laser.
- 6) Fibre Channel PI Standard.
- 7) Average optical power at which the BER is  $1 \times 10^{-12}$ . Measured with a  $2^7-1$  NRZ PRBS and ER = 9 dB.
- 8) An increase in optical power above the specified level will cause the LOS output to switch from a high state to a low state.
- 9) A decrease in optical power below the specified level will cause the LOS to change from a low state to a high state.

**I/O Timing of Soft Control and Status Functions**

Parameter	Symbol	Max. Value	Unit	Condition
Tx Disable assert time	t_off	100	ms	Time from Tx Disable bit set <sup>1)</sup> until optical output falls below 10% of nominal
Tx Disable deassert time	t_on	100	ms	Time from Tx Disable bit cleared until optical output rises above 90% of nominal
Time to initialize, including reset of Tx Fault	t_init	300	ms	Time from power on or negation of Tx Fault using Tx Disable until transmitter output is stable <sup>2)</sup>
Tx Fault assert time	t_fault	100	ms	Time from fault to Tx Fault bit set
LOS assert time	t_loss_on	100	ms	Time from LOS state to Rx LOS bit set
LOS deassert time	t_loss_off	100	ms	Time from non-LOS state to Rx LOS bit cleared
Rate select change time	t_rate_sel	100	ms	Time from change of state of Rate Select bit <sup>1)</sup> until receiver bandwidth is in conformance with appropriate specification
Serial ID clock rate <sup>3)</sup>	f_serial_clock	400	kHz	N/A
Analog parameter data ready	t_data	1000	ms	From power on to data ready, bit 0 of byte 110 set
Serial bus hardware ready	t_serial	300	ms	Time from power on until module is ready for data transmission

<sup>1)</sup> Measured from falling clock edge after stop bit of write transaction.

<sup>2)</sup> See Gigabit Interface Converter (GBIC). SFF-0053, Rev. 5.5, September 27, 2000.

<sup>3)</sup> The maximum clock rate of the serial interface is defined by the I<sup>2</sup>C bus interface standard.

**Eye Safety**

This laser based single mode transceiver is a Class 1 product. It complies with IEC 60825-1 and FDA 21 CFR 1040.10 and 1040.11.

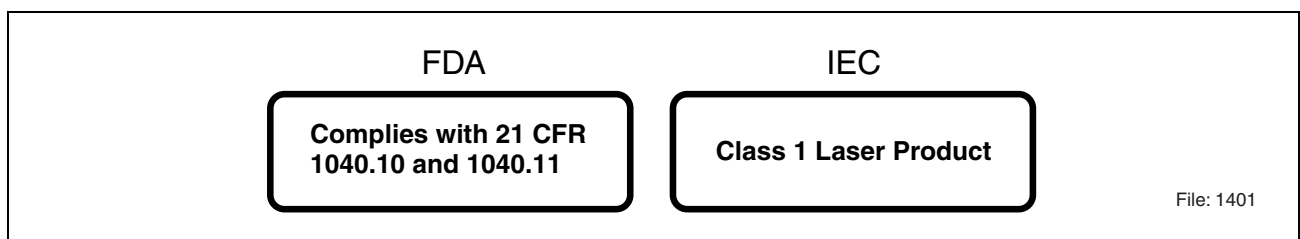
To meet laser safety requirements the transceiver shall be operated within the Absolute Maximum Ratings.

**Attention: All adjustments have been made at the factory prior to shipment of the devices. No maintenance or alteration to the device is required. Tampering with or modifying the performance of the device will result in voided product warranty.**

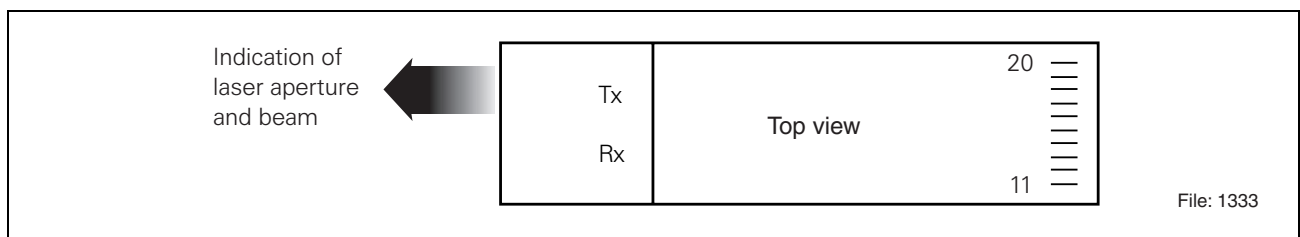
*Note: Failure to adhere to the above restrictions could result in a modification that is considered an act of “manufacturing”, and will require, under law, recertification of the modified product with the U.S. Food and Drug Administration (ref. 21 CFR 1040.10 (i)).*

**Laser Data**

Wavelength	1300 nm
Total Output Power (as defined by IEC: 7 mm aperture at 14 mm distance)	< 2 mW
Total Output Power (as defined by FDA: 7 mm aperture at 20 cm distance)	< 195 μW
Beam Divergence	6°



**Figure 3 Required Labels**



**Figure 4 Laser Emission**

## Application Notes

### EMI Recommendations

To avoid electromagnetic radiation exceeding the required limits set by the standards, please take note of the following recommendations.

When Gigabit switching components are found on a PCB (e.g. multiplexer, serializer-deserializer, clock data recovery, etc.), any opening of the chassis may leak radiation; this may also occur at chassis slots other than that of the device itself. Thus every mechanical opening or aperture should be as small as feasible and its length carefully considered.

On the board itself, every data connection should be an impedance matched line (e.g. strip line or coplanar strip line). Data (D) and Data-not (Dn) should be routed symmetrically. Vias should be avoided. Where internal termination inside an IC or a transceiver is not present, a line terminating resistor must be provided.

The decision of how best to establish a ground depends on many boundary conditions. This decision may turn out to be critical for achieving lowest EMI performance. At RF frequencies the ground plane will always carry some amount of RF noise. Thus the ground and  $V_{CC}$  planes are often major radiators inside an enclosure.

As a general rule, for small systems such as PCI cards placed inside poorly shielded enclosures, the common ground scheme has often proven to be most effective in reducing RF emissions. In a common ground scheme, the PCI card becomes more equipotential with the chassis ground. As a result, the overall radiation will decrease. In a common ground scheme, it is strongly recommended to provide a proper contact between signal ground and chassis ground at every location where possible. This concept is designed to avoid hotspots which are places of highest radiation, caused when only a few connections between chassis and signal grounds exist. Compensation currents would concentrate at these connections, causing radiation.

However, as signal ground may be the main cause for parasitic radiation, connecting chassis ground and signal ground at the wrong place may result in enhanced RF emissions. For example, connecting chassis ground and signal ground at a front panel/bezel/chassis by means of a fiber optic transceiver/cage may result in a large amount of radiation especially where combined with an inadequate number of grounding points between signal ground and chassis ground. Thus the transceiver becomes a single contact point increasing radiation emissions. Even a capacitive coupling between signal ground and chassis ground may be harmful if it is too close to an opening or an aperture. For a number of systems, enforcing a strict separation of signal ground from chassis ground may be advantageous, providing the housing does not present any slots or other discontinuities. This separate ground concept seems to be more suitable in large systems where appropriate shielding measures have also been implemented.

The return path of RF current must also be considered. Thus a split ground plane between Tx and Rx paths may result in severe EMI problems.

**Application Notes**

The bezel opening for a transceiver should be sized so that all contact springs of the transceiver cage make good electrical contact with the face plate.

Please consider that the PCB may behave like a dielectric waveguide. With a dielectric constant of 4, the wavelength of the harmonics inside the PCB will be half of that in free space. Thus even the smallest PCBs may have unexpected resonances.

Large systems can have many openings in the front panel for SFP transceivers. In typical applications, not all of these ports will hold transceivers; some may be intentionally left empty. These empty slots can emit significant amounts of radiation. Thus it is strongly recommended that empty ports be plugged with an EMI plug as shown in **Figure 5**. Infineon offers an EMI/dust plug, P/N V23818-S5-B1.

**Infineon Proposes**

**Cage:**

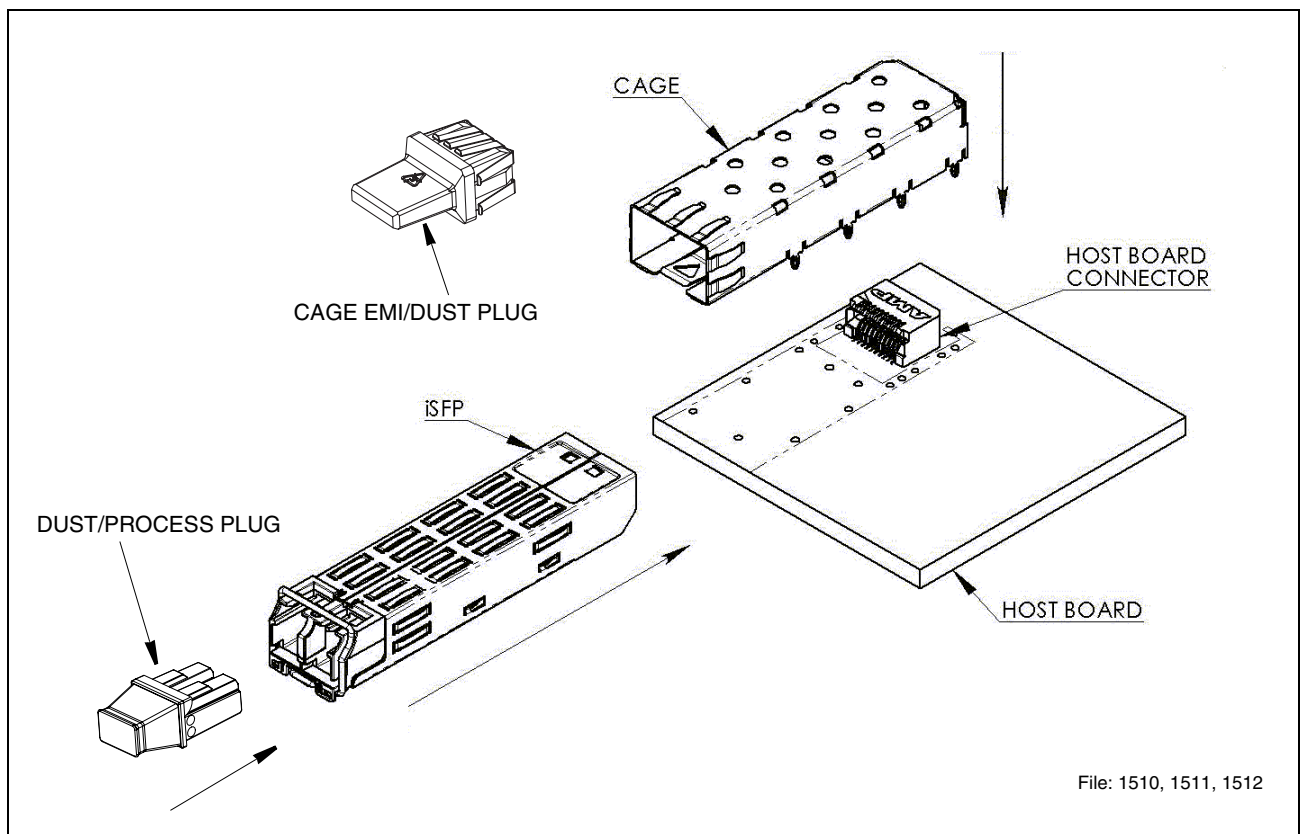
Infineon Technologies  
Part Number: V23838-S5-N1

**Host Board Connector:**

Tyco Electronics  
Part Number: 1367073-1

**Cage EMI/Dust Plug:**

Infineon Technologies  
Part Number: V23818-S5-B1



**Figure 5**



**EEPROM Serial ID Memory Contents (A0h)**

The data can be read using the 2-wire serial CMOS E2PROM protocol of the Atmel AT24C01A or equivalent.

Addr.	Hex	ASCII	Addr.	Hex	ASCII	Addr.	Hex	ASCII	Addr.	Hex	ASCII
0	03		32	20		64	00		96	20	
1	04		33	20		65	1A		97	20	
2	07		34	20		66	00		98	20	
3	00		35	20		67	32		99	20	
4	00		36	00		68 <sup>3)</sup>			100	20	
5	00		37	00		69 <sup>3)</sup>			101	20	
6	02		38	03		70 <sup>3)</sup>			102	20	
7	80		39	19		71 <sup>3)</sup>			103	20	
8	10		40	56	V	72 <sup>3)</sup>			104	20	
9	01		41	32	2	73 <sup>3)</sup>			105	20	
10	05		42	33	3	74 <sup>3)</sup>			106	20	
11	01		43	38	8	75 <sup>3)</sup>			107	20	
12	15		44	34	4	76 <sup>3)</sup>			108	20	
13	00		45	38	8	77 <sup>3)</sup>			109	20	
14	14		46	2D	-	78 <sup>3)</sup>			110	20	
15	C8		47	4D	M	79 <sup>3)</sup>			111	20	
16	1E		48	31	1	80 <sup>3)</sup>			112	20	
17	0F		49	35	5	81 <sup>3)</sup>			113	20	
18	00		50	2D	-	82 <sup>3)</sup>			114	20	
19	00		51	43	C	83 <sup>3)</sup>			115	20	
20	49	l	52	36	6	84 <sup>4)</sup>			116	20	
21	6E	n	53	35	5	85 <sup>4)</sup>			117	20	
22	66	f	54	36	6	86 <sup>4)</sup>			118	20	
23	69	i	55	20		87 <sup>4)</sup>			119	20	
24	6E	n	56	30	0 <sup>2)</sup>	88 <sup>4)</sup>			120	20	
25	65	e	57	31	1 <sup>2)</sup>	89 <sup>4)</sup>			121	20	
26	6F	o	58	2E	.	90 <sup>4)</sup>			122	20	
27	6E	n	59	30	0 <sup>2)</sup>	91 <sup>4)</sup>			123	20	
28	20		60	05		92 <sup>5)</sup>	68		124	20	
29	41	A	61	1E		93 <sup>6)</sup>	B0		125	20	
30	47	G	62	00		94	01		126	20	
31	20		63 <sup>1)</sup>			95 <sup>7)</sup>			127	20	

- 1) Address 63 is check sum of bytes 0 - 62.
- 2) Version number will vary depending on product status.
- 3) Address 68 - 83 Vendor Serial Number.
- 4) Date code.
- 5) Diagnostic Monitoring Type, if and how implemented.
- 6) Enhanced Options, if any implemented.
- 7) Address 95 is check sum of bytes 64 - 94.

**Digital Diagnostic Monitoring Interface – Intelligent**
**Alarm and Warning Thresholds (2-Wire Address A2h)**

<b>Address</b>	<b># Bytes</b>	<b>Name</b>	<b>Description</b>	<b>Value</b>
00 - 01	2	Temp High Alarm	MSB at low address	90°C <sup>1)</sup>
02 - 03	2	Temp Low Alarm	MSB at low address	-30°C
04 - 05	2	Temp High Warning	MSB at low address	85°C <sup>1)</sup>
06 - 07	2	Temp Low Warning	MSB at low address	-20°C
08 - 09	2	Voltage High Alarm	MSB at low address	3.7 V
10 - 11	2	Voltage Low Alarm	MSB at low address	2.95 V
12 - 13	2	Voltage High Warning	MSB at low address	3.63 V
14 - 15	2	Voltage Low Warning	MSB at low address	2.97 V
16 - 17	2	Bias High Alarm	MSB at low address	t.b.d.
18 - 19	2	Bias Low Alarm	MSB at low address	t.b.d.
20 - 21	2	Bias High Warning	MSB at low address	t.b.d.
22 - 23	2	Bias Low Warning	MSB at low address	t.b.d.
24 - 25	2	Tx Power High Alarm	MSB at low address	1 dBm
26 - 27	2	Tx Power Low Alarm	MSB at low address	-8 dBm
28 - 29	2	Tx Power High Warning	MSB at low address	0 dBm
30 - 31	2	Tx Power Low Warning	MSB at low address	-7 dBm
32 - 33	2	Rx Power High Alarm	MSB at low address	-1 dBm
34 - 35	2	Rx Power Low Alarm	MSB at low address	-22 dBm
36 - 37	2	Rx Power High Warning	MSB at low address	0 dBm
38 - 39	2	Rx Power Low Warning	MSB at low address	-21 dBm
40 - 55	16	Reserved	Reserved for future monitored quantities	

<sup>1)</sup> A delta exists between actual transceiver temperature and value shown as measurement is taken internal to an IC located on the underside of the iSFP PCB.

**Alarm and Warning Flags (2-Wire Address A2h)**

Byte	Bit	Name	Description
112	7	Temp High Alarm	Set when internal temperature exceeds high alarm level
112	6	Temp Low Alarm	Set when internal temperature is below low alarm level
112	5	V <sub>CC</sub> High Alarm	Set when internal supply voltage exceeds high alarm level
112	4	V <sub>CC</sub> Low Alarm	Set when internal supply voltage is below low alarm level
112	3	Tx Bias High Alarm	Set when Tx Bias current exceeds high alarm level
112	2	Tx Bias Low Alarm	Set when Tx Bias current is below low alarm level
112	1	Tx Power High Alarm	Set when Tx output power exceeds high alarm level
112	0	Tx Power Low Alarm	Set when Tx output power is below low alarm level
113	7	Rx Power High Alarm	Set when received power exceeds high alarm level
113	6	Rx Power Low Alarm	Set when received power is below low alarm level
113	5	Reserved Alarm	
113	4	Reserved Alarm	
113	3	Reserved Alarm	
113	2	Reserved Alarm	
113	1	Reserved Alarm	
113	0	Reserved Alarm	
114	All	Reserved	
115	All	Reserved	
116	7	Temp High Warning	Set when internal temperature exceeds high warning level
116	6	Temp Low Warning	Set when internal temperature is below low warning level
116	5	V <sub>CC</sub> High Warning	Set when internal supply voltage exceeds high warning level

**Alarm and Warning Flags (2-Wire Address A2h) (cont'd)**

<b>Byte</b>	<b>Bit</b>	<b>Name</b>	<b>Description</b>
116	4	V <sub>CC</sub> Low Warning	Set when internal supply voltage is below low warning level
116	3	Tx Bias High Warning	Set when Tx bias current exceeds high warning level
116	2	Tx Bias Low Warning	Set when Tx bias current is below low warning level
116	1	Tx Power High Warning	Set when Tx output power exceeds high warning level
116	0	Tx Power Low Warning	Set when Tx output power is below low warning level
117	7	Rx Power High Warning	Set when received power exceeds high warning level
117	6	Rx Power Low Warning	Set when received power is below low warning level
117	5	Reserved Warning	
117	4	Reserved Warning	
117	3	Reserved Warning	
117	2	Reserved Warning	
117	1	Reserved Warning	
117	0	Reserved Warning	
118	All	Reserved	
119	All	Reserved	

**A/D Values and Status Bits (2-Wire Address A2h)**

Byte	Bit	Name	Description
Converted analog values. Calibrated 16 bit data.			
96	All	Temperature MSB	Internally measured module temperature <sup>1)</sup>
97	All	Temperature LSB	
98	All	V <sub>CC</sub> MSB	Internally measured supply voltage in transceiver <sup>2)</sup>
99	All	V <sub>CC</sub> LSB	
100	All	Tx Bias MSB	Internally measured Tx Bias Current <sup>3)</sup>
101	All	Tx Bias LSB	
102	All	Tx Power MSB	Measured Tx output power <sup>4)</sup>
103	All	Tx Power LSB	
104	All	Rx Power MSB	Measured Rx input power <sup>5)</sup>
105	All	Rx Power LSB	
106	All	Reserved MSB	Reserved for 1st future definition of digitized analog input
107	All	Reserved LSB	Reserved for 1st future definition of digitized analog input
108	All	Reserved MSB	Reserved for 2nd future definition of digitized analog input
109	All	Reserved LSB	Reserved for 2nd future definition of digitized analog input

<sup>1)</sup> Temperature measurement is performed on an IC located on the underside of the iSFP PCB. The accuracy is  $\pm 3^{\circ}\text{C}$ .

<sup>2)</sup> The Tx voltage V<sub>CC</sub>T is monitored, with accuracy of  $\pm 3\%$ .

<sup>3)</sup> The accuracy of bias current measurement is  $\pm 10\%$ .

<sup>4)</sup> The accuracy of the Tx optical power measurement is  $\pm 1$  dB.

<sup>5)</sup> The accuracy of the Rx optical power measurement is  $\pm 3$  dB.

Single Mode 1300 nm iSFP Transceiver, AC/AC TTL

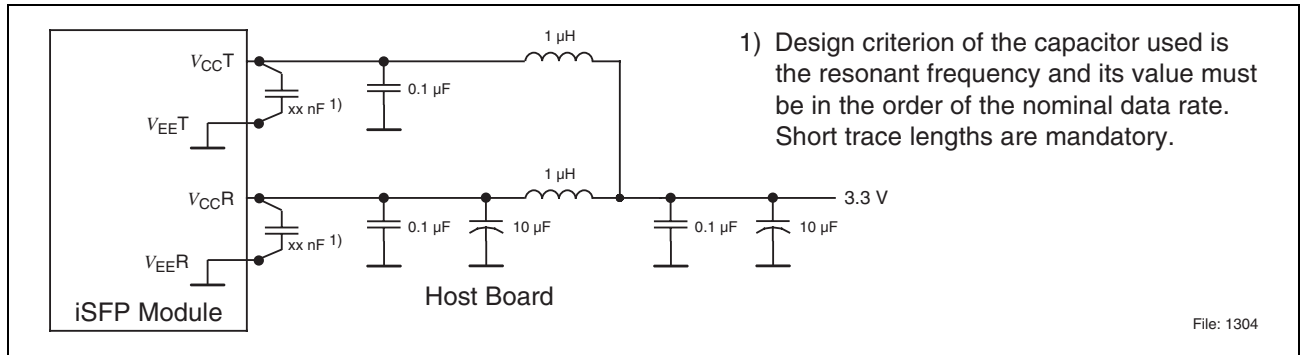


Figure 6 Recommended Host Board Supply Filtering Network

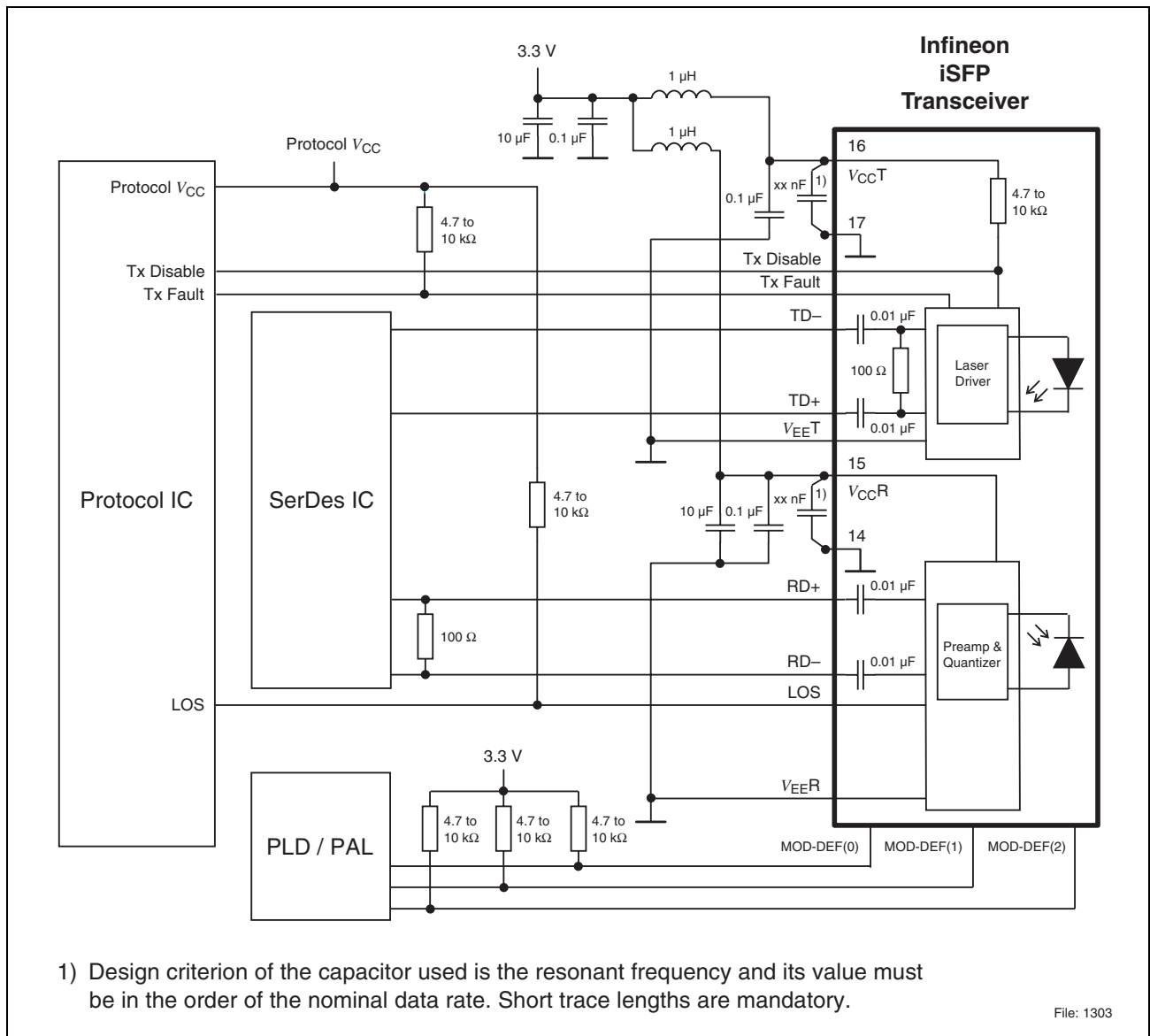


Figure 7 Example iSFP Host Board Schematic

Package Outlines

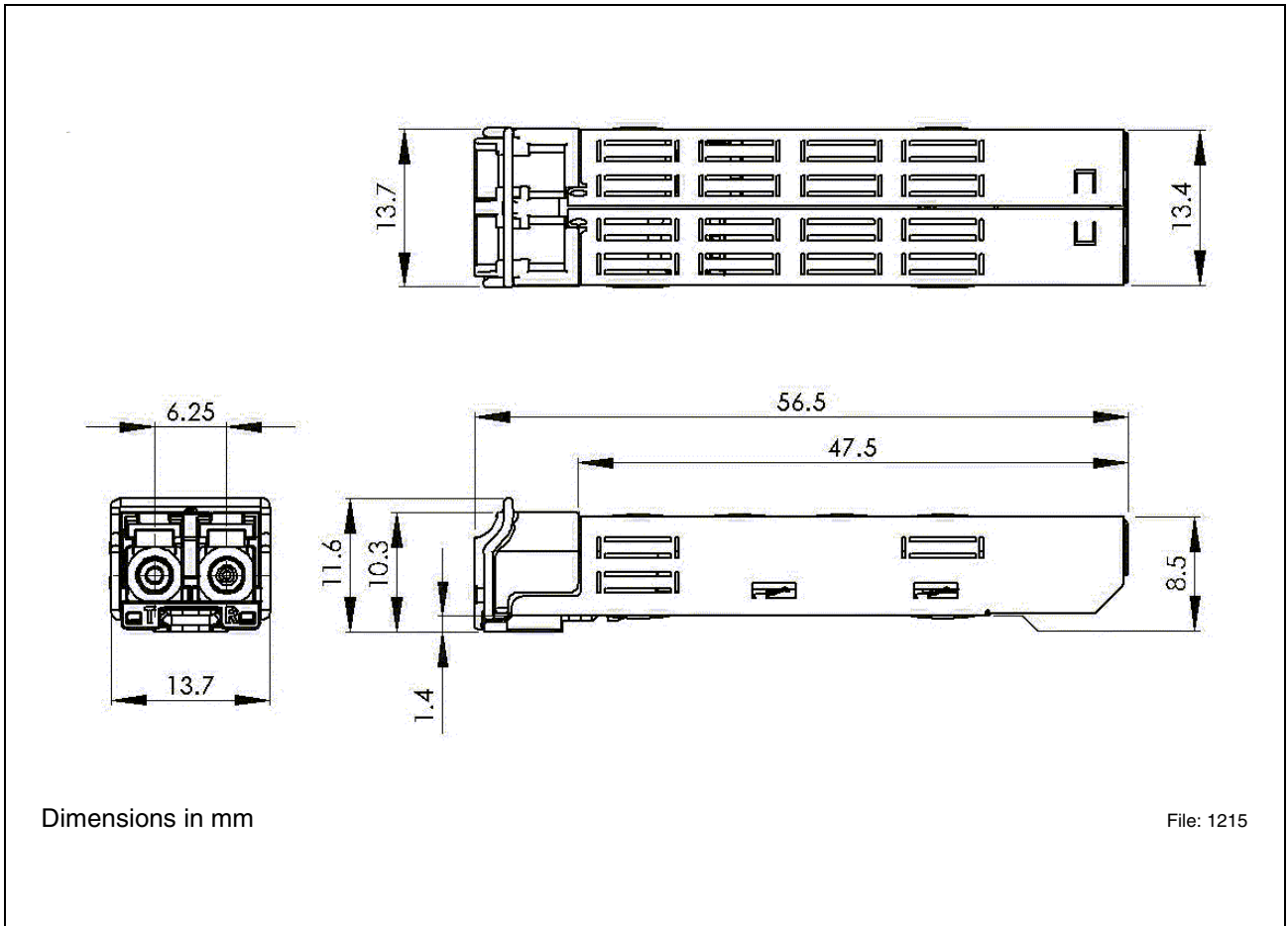


Figure 8

**Revision History: 2003-04-09**

DS0

Previous Version: 2003-04-09

<b>Page</b>	<b>Subjects (major changes since last revision)</b>

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